Peak to Peak Jitter (tPK)

**Storage Temperature Range** 

**Start Up Time** 





#### EMK13 H 2 H -29.555M

Series —
RoHS Compliant (Pb-free) 4 Pad 5mm x 7mm SMD
3.3Vdc LVCMOS MEMS Oscillator

#50ppm Maximum over -40°C to +85°C

Nominal Frequency 29.555MHz

Output Control Function

Tri-State (Disabled Output: High Impedance)

Duty Cycle -50 ±5(%)

250pSec Maximum, 100pSec Typical

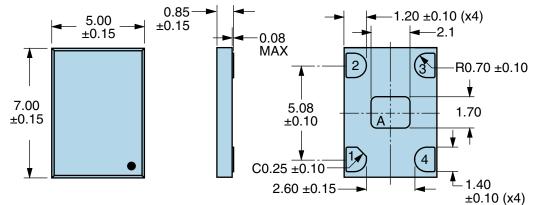
50mSec Maximum -55°C to +125°C

**ELECTRICAL SPECIFICATIONS Nominal Frequency** 29.555MHz Frequency Tolerance/Stability ±50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration) Aging at 25°C ±1ppm Maximum First Year **Operating Temperature Range** -40°C to +85°C Supply Voltage 3.3Vdc ±10% **Input Current** 25mA Maximum Output Voltage Logic High (Voh) 90% of Vdd Minimum (IOH=-8mA) **Output Voltage Logic Low (Vol)** 10% of Vdd Maximum (IOL=+8mA) Rise/Fall Time 2nSec Maximum (Measured from 20% to 80% of waveform) **Duty Cycle** 50 ±5(%) (Measured at 50% of waveform) **Load Drive Capability** 15pF Maximum **Output Logic Type CMOS Output Control Function** Tri-State (Disabled Output: High Impedance) **Output Control Input Voltage** +0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS			
ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V		
Flammability	UL94-V0		
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G		
Moisture Resistance	MIL-STD-883, Method 1004		
Moisture Sensitivity Level	J-STD-020, MSL 1		
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K		
Resistance to Solvents	MIL-STD-202, Method 215		
Solderability	MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only)		
Temperature Cycling	MIL-STD-883, Method 1010, Condition B		
Thermal Shock	MIL-STD-883, Method 1011, Condition B		
Vibration	MIL-STD-883, Method 2007, Condition A, 20G		



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



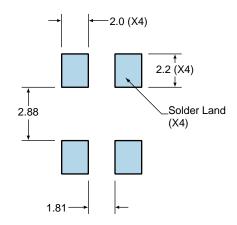
Note A: Center paddle is connected
internally to oscillator ground (Pad 2).

PIN	CONNECTION
1	Tri-State (High Impedance)
1	Power Down (Logic Low)
2	Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	XXXX or XXXXX
	XXXX or XXXXX=Ecliptek Manufacturing Lot Code
	Manufacturing Lot Code

### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



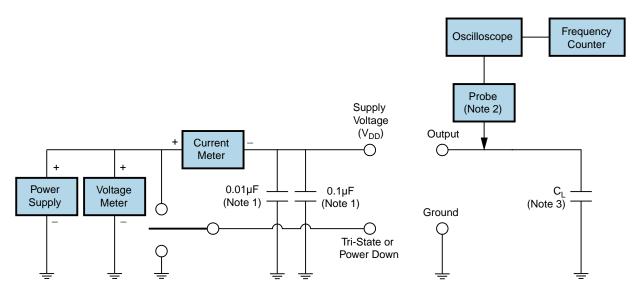
All Tolerances are ±0.1



#### **OUTPUT WAVEFORM & TIMING DIAGRAM**



### **Test Circuit for CMOS Output**



- Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### **High Temperature Infrared/Convection**

T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	150°C
- Temperature Typical (T <sub>s</sub> TYP)	175°C
- Temperature Maximum (T <sub>S</sub> MAX)	200°C
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	N/A
- Temperature Typical (T <sub>S</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

## Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.